## Hex 3-State Noninverting Buffer with Common Enables and LSTTL Compatible Inputs

## High-Performance Silicon-Gate CMOS

The MC74HCT365A is identical in pinout to the LS365. The device inputs are compatible with LSTTL outputs.

This device is a high-speed hex buffer with 3-state outputs and two common active-low Output Enables. When either of the enables is high, the buffer outputs are placed into high-impedance states. The HCT365A has noninverting outputs.

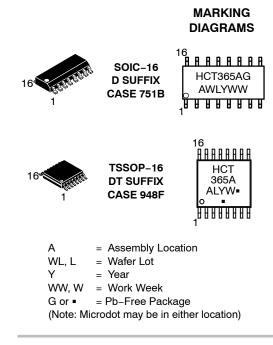
#### Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 90 FETs or 22.5 Equivalent Gates
- These are Pb-Free Devices\*



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#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

	1•	16	v <sub>cc</sub>
A0 [	2	15	OUTPUT ENABLE 2
Y0 [	3	14	] A5
A1 [	4	13	] Y5
Y1 [	5	12	] A4
A2 [	6	11	] Y4
Y2 [	7	10	] A3
GND [	8	9	] Y3

Figure 1. Pin Assignment

#### **FUNCTION TABLE**

Inputs			Output
Enable 1	Enable 2	А	Y
L	L	L	L
L	L	н	н
н	Х	Х	Z
X	Н	Х	Z

X = don't care

Z = high impedance

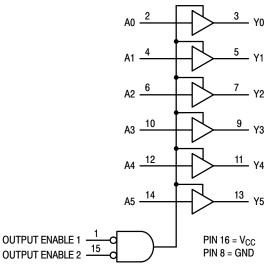


Figure 2. Logic Diagram

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC74HCT365ADG	SOIC-16 (Pb-Free)	48 Units / Rail
MC74HCT365ADR2G	SOIC-16 (Pb-Free)	2500 Units / Reel
MC74HCT365ADTG	TSSOP-16* (Pb-Free)	96 Units / Rail
MC74HCT365ADTR2G	TSSOP-16* (Pb-Free)	2500 Units / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*This package is inherently Pb-Free.

#### MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	$-0.5$ to V_{CC} + 0.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	$-$ 0.5 to V_{CC} + 0.5	V
I <sub>in</sub>	DC Input Current, per Pin	± 20	mA
I <sub>out</sub>	DC Output Current, per Pin	± 25	mA
I <sub>CC</sub>	DC Supply Current, $V_{CC}$ and GND Pins	± 50	mA
P <sub>D</sub>	Power Dissipation in Still Air, SOIC Package TSSOP Package		mW
T <sub>stg</sub>	Storage Temperature	– 65 to + 150	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Derating — SOIC Package: - 7 mW/°C from 65° to 125°C

TSSOP Package: - 6.1 mW/°C from 65° to 125°C

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range, All Package Types	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise/Fall Time (Figure 1)	0	500	ns

#### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Gua	ranteed Li	mit	
Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	– 55 to 25°C	≤ <b>85°C</b>	≤ 125°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage	$\begin{array}{l} V_{out} = V_{CC} - 0.1 \ V \\  I_{out}  \ \leq \ 20 \ \mu A \end{array}$	4.5 to 5.5	2.0	2.0	2.0	V
V <sub>IL</sub>	Maximum Low-Level Input Voltage	$V_{out} = 0.1 V$ $ I_{out}  \le 20 \mu A$	4.5 to 5.5	0.8	0.8	0.8	V
V <sub>OH</sub>	Minimum High-Level Output Voltage	$V_{in} = V_{IH}$ $ I_{out}  \le 20 \ \mu A$	4.5	4.4	4.4	4.4	V
		$V_{in} = V_{IH}$ $ I_{out}  \le 6.0 \text{ mA}$	4.5	3.98	3.84	3.70	
V <sub>OL</sub>	Maximum Low-Level Output Voltage	$V_{in} = V_{IL}$ $ I_{out}  \le 20 \ \mu A$	4.5	0.1	0.1	0.1	V
		$V_{in} = V_{IL}$ $ I_{out}  \le 6.0 \text{ mA}$	4.5	0.26	0.33	0.40	
l <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = V <sub>CC</sub> or GND	4.5	±0.1	±1.0	±1.0	μA
I <sub>OZ</sub>	Maximum Three-State Leakage Current	Output in High–Impedance State $V_{in} = V_{IL}$ or $V_{IH}$ $V_{out} = V_{CC}$ or GND	4.5	±0.5	±5.0	±10	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC} \text{ or GND}$ $I_{out} = 0 \ \mu A$	4.5	4	40	160	μA
$\Delta I_{CC}$	Additional Quiescent Supply Current	$V_{in}$ = 2.4V, Any One Input $V_{in}$ = V <sub>CC</sub> or GND, Other Inputs		≥ <b>-55°C</b>	25 to	0 125°C	
		$I_{out} = 0\mu A$	5.5	2.9	2	2.4	mA

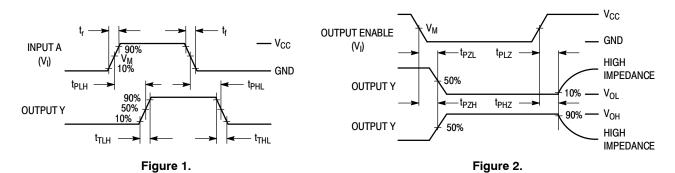
			Guaranteed Limit			
Symbol	Parameter	V <sub>CC</sub> V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 3)	4.5	24	30	36	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 2 and 4)	4.5	44	55	66	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 2 and 4)	4.5	44	55	66	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 3)	4.5	12	15	18	ns
C <sub>in</sub>	Maximum Input Capacitance	_	10	10	10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance (Output in High-Impedance State)	-	15	15	15	pF
			Typical	@ 25°C, V <sub>C</sub>	<sub>C</sub> = 5.0 V	
C <sub>PD</sub>	Power Dissipation Capacitance (Per Buffer)*			60		pF

#### **AC ELECTRICAL CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

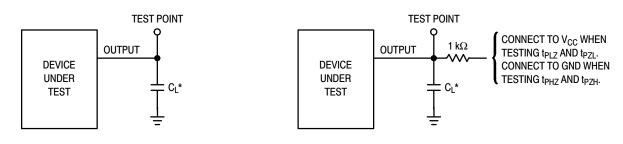
\* Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

#### SWITCHING WAVEFORMS

(V<sub>I</sub> = 0 to 3 V, V<sub>M</sub> = 1.3 V)



#### **TEST CIRCUITS**



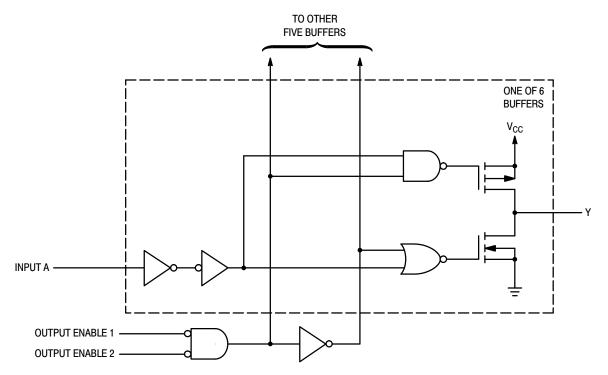
\*Includes all probe and jig capacitance

#### Figure 3.

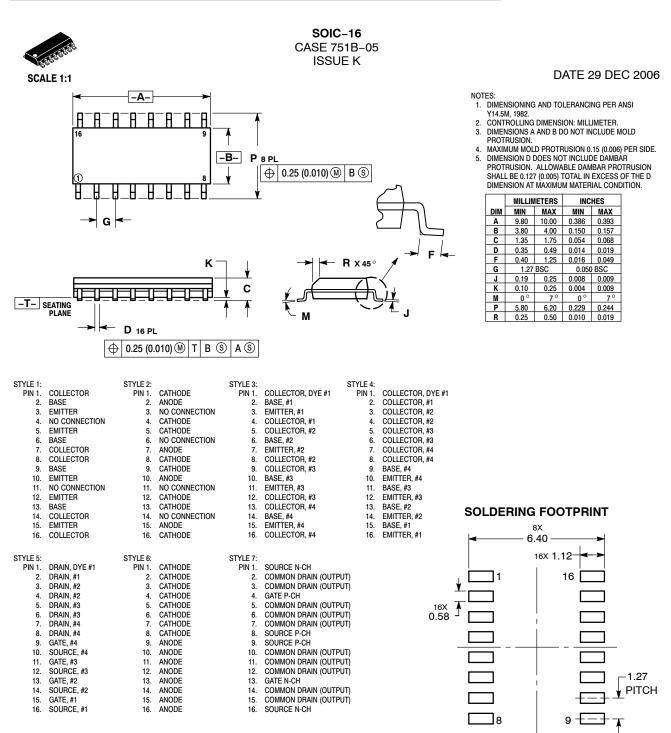
Figure 4.

\*Includes all probe and jig capacitance

LOGIC DETAIL





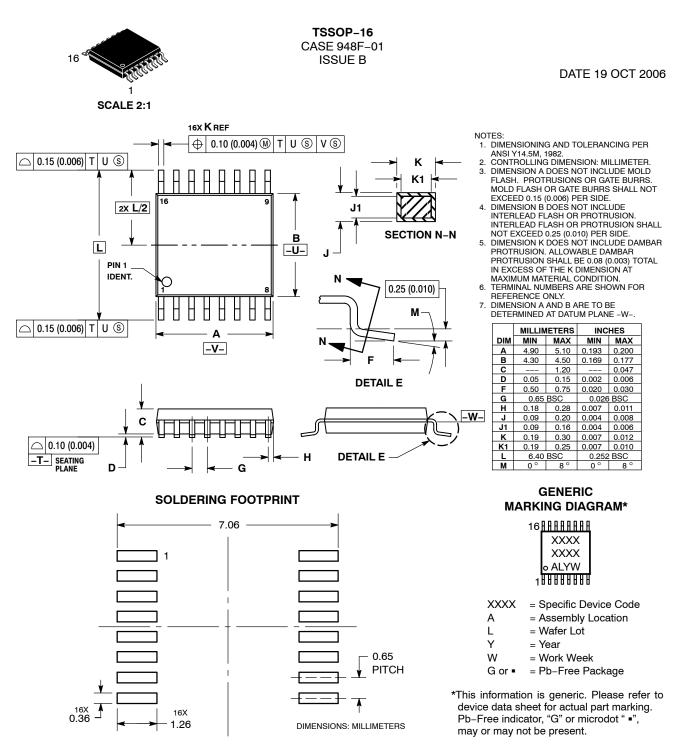


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